

Vishay Siliconix

N-Channel 30 V (D-S) MOSFET

DESCRIPTION

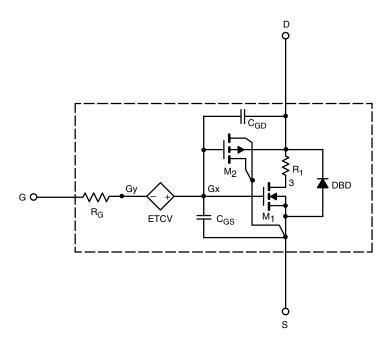
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model SiR818DP

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9.6

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.3	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 20 A	0.0023	0.0023	Ω
		$V_{DS} = 4.5 \text{ V}, I_D = 20 \text{ A}$	0.0027	0.0027	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 20 A	104	104	S
Diode Forward Voltage	V_{SD}	I _S = 4 A	0.71	0.71	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	3600	3660	pF
Output Capacitance	C _{oss}		730	710	
Reverse Transfer Capacitance	C _{rss}		306	290	
Total Gate Charge	Qg	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 20 A	60	63	
			31	30.5	nC
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$	8.3	8.3	
		1			

Notes

Gate-Drain Charge

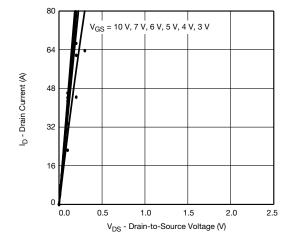
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

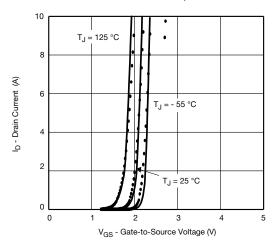
 Q_{gd}

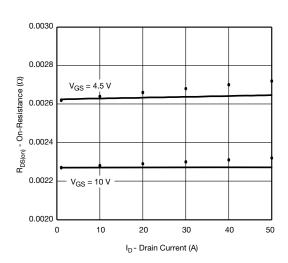
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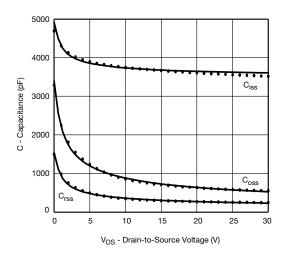
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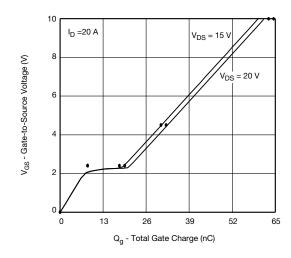
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25 \, ^{\circ}\text{C}$, unless otherwise noted)

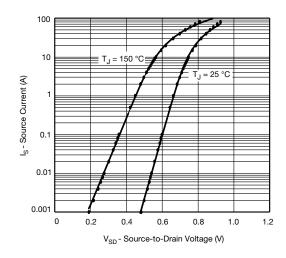












Note

• Dots and squares represent measured data.



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